

Cite this: *Sustainable Energy Fuels*,
2023, 7, 1302Received 22nd October 2022
Accepted 7th January 2023

DOI: 10.1039/d2se01475k

rsc.li/sustainable-energy

Enabling a rapid SnO₂ chemical bath deposition process for perovskite solar cells†

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Chemical bath deposition (CBD) is a common method to fabricate SnO₂ electron-transport layers in perovskite solar cells. However, this typically requires long deposition times, which is a significant drawback for the eventual commercialisation of perovskite solar cells. By applying ultrasonication during the chemical bath deposition process, higher rates of heterogenous nucleation were triggered, which accelerated the CBD process without sacrificing coverage. Deposition times of 15 min, 30 min and 45 min were investigated and 30 minutes was determined to be the optimal duration for the ultrasonication assisted chemical bath deposition with the current parameters.

Introduction

Tin(IV) oxide (SnO₂) is one of the few common metal oxides that can be used as an electron-transport layer (ETL) in perovskite solar cells (PSCs). Its optimal conduction band level relative to lead-halide perovskite,¹ high electron mobility,² and low-temperature processing (180 °C)³ put it at an advantageous position against other common metal oxides, such as titanium dioxide (TiO₂). A variety of techniques for its thin-film fabrication exist in the current literature, namely the spin-coating of an alcoholic-sol,³ spin-coating or large-scale coating of a nanoparticle suspension,^{4,5} atomic-layer deposition,¹ combustion synthesis,⁶ and chemical bath deposition.^{7,8} Among the variety of techniques reported thus far, chemical bath deposition (CBD) is an attractive option due to its simple and coating homogeneity at lower capital costs.⁹ The CBD process involves the dipping of substrates into a precursor solution, where thin film nucleation and growth are initiated by the reaction taking place on the surface of the substrates. These processes can be modulated *via* the control of various factors, such as precursor solution concentration, pH, and temperature. First used in the manufacturing of PbS and PbSe thin-films for infrared detectors,⁹ CBD has been now most commonly associated with the

fabrication of CdS films as the n-type material for second-generation solar panels.¹⁰ Ortega-Borges and Lincot,¹¹ for example, distinguished between two stages of growth: (i) an atom-by-atom growth process, where Cd(OH)₂ in the precursor solution adsorbs onto the surface of the substrate and reacts there to form CdS; and (ii) a colloidal-growth stage, where homogeneous nucleation occurs and large precipitates are deposited onto the films.

The use of CBD to fabricate the SnO₂ ETL layer for PSCs was first demonstrated by Anaraki and co-workers back in 2016.⁷ It was shown that a mixture of urea, hydrochloric acid, water, and tin(II) chloride, with thioglycolic acid as the complexing agent, could be used as a precursor bath for SnO₂ thin-film growth. For high-quality thin films to be obtained, a much lower precursor concentration relative to that utilised in CBD of the CdS layer¹¹ was required due to the propensity of high SnCl₂ concentrations to accelerate the reaction, causing the formation of large agglomerates and uneven film growth. The low concentration solution, however, resulted in an extended deposition time of 3 h. In addition, it could not produce a layer of SnO₂ that completely covered the substrate within a single CBD process. Thus, a combination of spin-coating and CBD was needed to obtain the best coverage for the SnO₂ films, and they achieved a high efficiency of 20.8% with 92% of their devices working. In contrast, Ko *et al.*¹² demonstrated a process that utilised a concentration of up to 0.12 M, ten times that of the concentration used by Anaraki *et al.* (0.012 M). It was reasoned that increasing the concentration promotes the formation of more uniform SnO₂ colloid sizes in the precursor solution due to competing growth processes amongst the particles, leading to smoother and pinhole-free SnO₂ films. However, their initial CBD step required the dissolution of SnCl₂ in ethanol, followed by the storage of the resulting solution in a freezer. The role of this additional step, however, remains unclear and it introduces

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† Electronic supplementary information (ESI) available: XPS quantification, XPS data for Th-SnO₂ and powdered SnO₂; full device data; cross-sectional SEM images of devices; XRD and GIWAXS data for perovskite film coated on the SnO₂ layers; IPCE, transmission and absorption data for SnO₂ layers, study on concentration effect on device properties, comparison of device data with spin-coated colloidal SnO₂. See DOI: <https://doi.org/10.1039/d2se01475k>



an additional factor that needs to be controlled, *e.g.*, the growth rate of the colloids in the alcoholic precursor and possible aging effects.

More recently, Yoo *et al.*¹³ proposed that the pH of the precursor solution played a major role in the quality of SnO₂ produced. A reaction route was proposed, showing how the SnCl₂ species could be oxidised to SnO₂ by the dissolved oxygen in the solution. It was believed that heterogenous nucleation occurred at the beginning of the process, allowing for conformal growth at lower concentration, justifying the use of a low concentration of precursor solution in their case. Although it contradicts the claim made by Ko *et al.*,¹² who posited that higher concentrations are required to avoid heterogenous nucleation for high quality films, good SnO₂ coverage and highly efficient PSCs could still be achieved with the method devised by Yoo *et al.* However, the champion devices were fabricated by performing the CBD process three times, with a fresh precursor solution used each time. This avoids the homogeneous nucleation growth stage, although the total duration required for the entire process was 6 h. While the technique was similar to that used by Zhang *et al.*,¹⁴ where the CBD was done twice for the fabrication of efficient large-area PSCs, the need for repeated CBD cycles increases the time for the already slow process, and as such, hampers commercialisation.

Spurred by the aforementioned studies, we sought an extrinsic approach to accelerate the CBD of SnO₂ films without multiple deposition processes. Specifically, ultrasonication, which utilises low-frequency ultrasound, was chosen because it can facilitate the thin film formation through the generation of cavitation bubbles¹⁵ capable of serving as nucleation spots, especially in the presence of a heterogenous surface^{16,17} (Fig. 1a). While being beneficial in terms of increasing the rate of heterogenous nucleation (and in turn, the speed of the reaction), ultrasonication concurrently maintains the circulation of reactants within the precursor solution.¹⁸ This eventually can contribute to a high degree of SnO₂ film coverage. Although the sonochemical synthesis of SnO₂ nanoparticles has been demonstrated before,¹⁹ the synthesis of SnO₂ thin films for the purposes of fabricating an ETL for perovskite solar cells has not been demonstrated in the literature. We note that

ultrasonication has been utilised for CdS films by Choi *et al.*, where they showed that the ultrasonication prevented large agglomerations of CdS from attaching to the substrate surface, whilst promoting the formation of a compact, homogenous layer of CdS.²⁰

In this work, a comparative study was performed between SnO₂ films made *via* the ultrasonication-assisted CBD and standard CBD. Devices based on the n-i-p architecture (Fig. 1b) were then fabricated from these films, and the device performances were compared.

Results and discussion

Characterisation of SnO₂ film coverage

To assess the viability of using ultrasonication to speed up the CBD process, we first investigated the coverage of SnO₂ on FTO substrates using the cyclic voltammetry method suggested by Kavan *et al.* First pioneered by Kavan *et al.* in 2014 (ref. 21) to investigate TiO₂ ETLs in dye-sensitized solar cells, and later applied to SnO₂ atomic layer deposited films,²² the technique relies on the fact that the SnO₂-electrolyte junction is diode-like, blocking current flow in one direction, whereas the FTO-electrolyte junction does not share this property. This difference can be observed by performing cyclic voltammetry measurements with a standard redox couple, as long as the redox potential is lower than the flatband potential of SnO₂.²² We investigated three different sonication durations – 15 min (15-SnO₂), 30 min (30-SnO₂), and 45 min (45-SnO₂), and compared them with bare FTO. We note that several different recipes for CBD have been adopted by various groups. Anaraki *et al.* added 0.5 g of urea, 0.108 g SnCl₂·2H₂O, 10 μL of thioglycolic acid, and 500 μL of hydrochloric acid in 40 mL of water, and the deposition was done at 70 °C, although they claimed that a diluted version (by 6 times) of their recipe had better reproducibility.⁷ On the other hand, Yoo *et al.* used similar concentrations, but the CBD was done at a higher temperature of 90 °C.¹³ We have therefore decided to base our studies on our current optimised recipe for CBD, except that a slightly higher concentration of SnCl₂·2H₂O was used (0.0033 M).²³

Fig. 2b shows the cyclic voltammograms of the sonicated SnO₂ samples – 15-SnO₂, 30-SnO₂, and 45-SnO₂. The SnO₂-

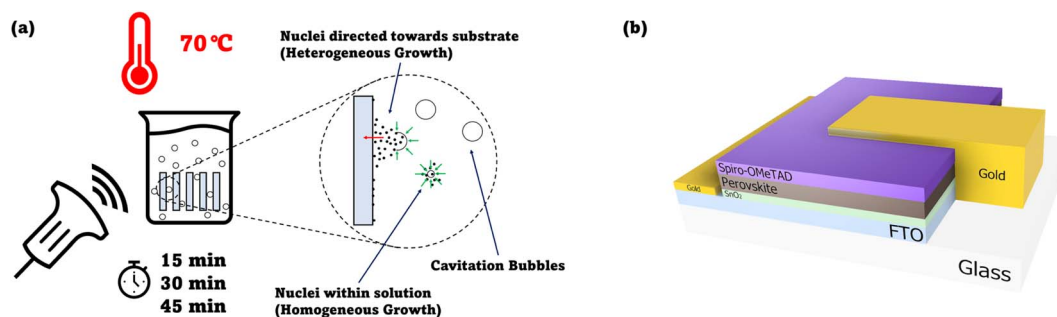


Fig. 1 (a) Suggested mechanism of cavitation improving the heterogenous crystallisation occurring on the substrate, leading to improved SnO₂ coverage. Diagram shows a beaker containing the chemical bath precursor with substrates immersed in it (placed vertically). An ultrasound probe signifies the application of ultrasound waves to the beaker. A detailed diagram of the methodology employed can be found in Fig. S1.† (b) Cross-section schematic of the n-i-p device architecture employed in this study.



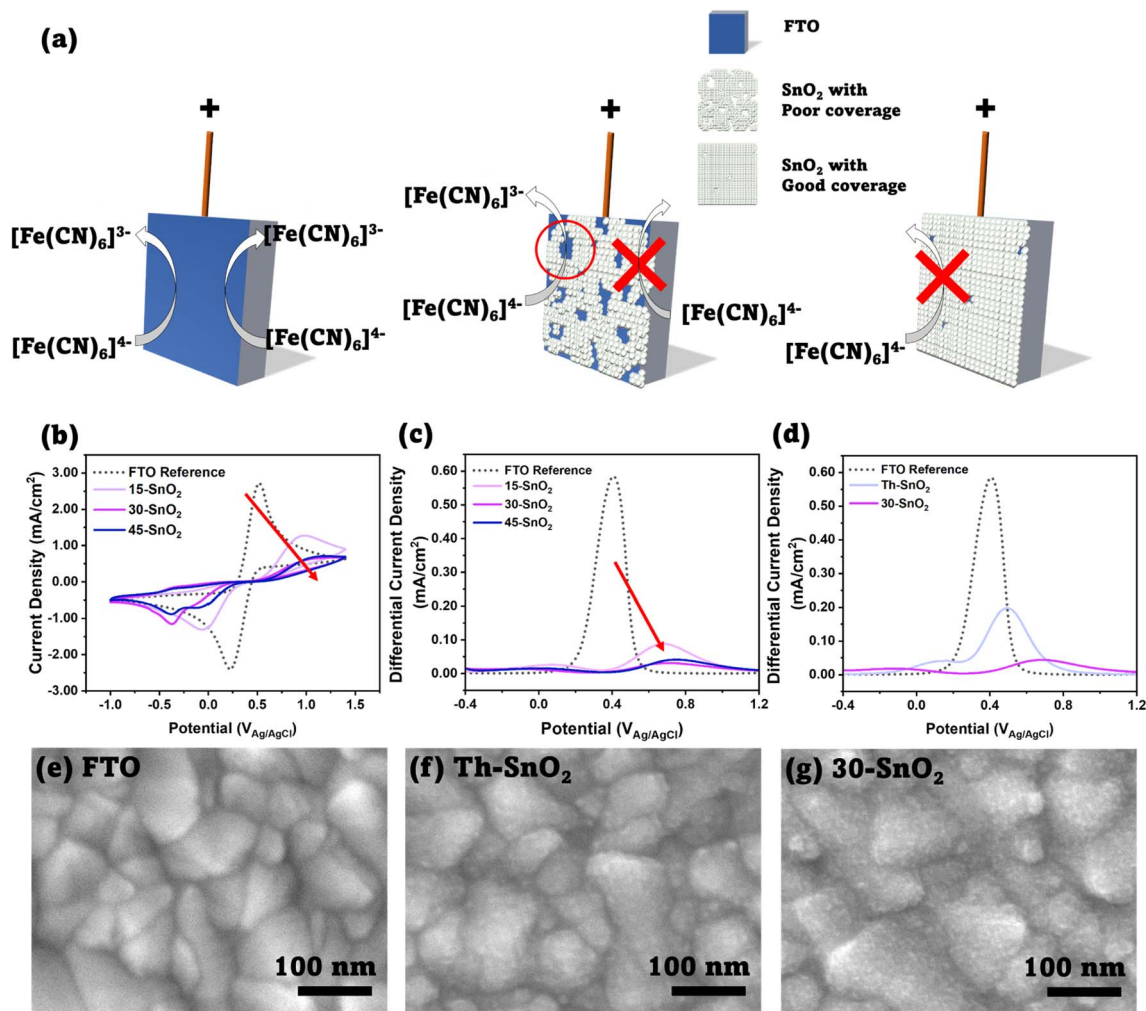


Fig. 2 (a) Schematic showing the principle behind the cyclic voltammetry method, as discussed by Kavan *et al.*²⁰ Left image shows a bare FTO substrate, where oxidation of $[\text{Fe}(\text{CN})_6]^{4-}$ to $[\text{Fe}(\text{CN})_6]^{3-}$ can occur. Middle image shows an FTO substrate partially covered by SnO_2 ; the SnO_2 blocks the reaction, but the exposed FTO allows the reaction, thus an increase in faradaic current is expected in the cyclic voltammogram. Right image shows complete coverage, where almost no oxidation reaction is expected to occur. (b) Cyclic voltammograms of FTO, 15-SnO₂, 30-SnO₂, and 45-SnO₂. The decreasing oxidation peaks (IUPAC convention) with increased sonication time, as shown with the red arrow, indicates improved SnO_2 coverage with increasing sonication time. (c) Differential pulse voltammograms for (a). A similar trend showing a decrease in the main peak can be observed with increasing sonication time. (d) Differential pulse voltammograms for FTO, Th-SnO₂, and 30-SnO₂, showing improved coverage from the sonication method, as opposed to a conventional CBD process at the same temperature and duration (30 minutes). (e)–(g) Top-view SEM images of FTO, Th-SnO₂ and 30-SnO₂. 30-SnO₂ shows a rougher surface as compared to Th-SnO₂, indicating the presence of more SnO_2 due to sonication, and therefore illustrating the effect of sonication. Scale bar is 100 nm.

electrolyte junction blocks the flow of electrons from the electrolyte to SnO_2 . Therefore, a complete absence of the oxidation peak suggests complete coverage of SnO_2 on FTO. The cyclic voltammograms suggest that all three sonicated samples have SnO_2 coated on them, since the oxidation peaks are lower than that of FTO. An additional reduction peak is noted for 30-SnO₂ and 45-SnO₂, whose origin is unclear and may be attributed to residual oxygen in the electrolyte being used. However, our coverage analysis focuses on the oxidation peak in line with the approach by Kavan *et al.*²¹

Additionally, it shows that while 30-SnO₂ and 45-SnO₂ have better coverage than 15-SnO₂, there is little improvement in coverage between 30-SnO₂ and 45-SnO₂. SEM images of the top surface (Fig. S2†) also reveal that 45-SnO₂ has an uneven

morphology with large agglomerations on the surface compared to 30-SnO₂, which may be detrimental to device performance. This suggests that the maximum coverage possible with the sonication technique is likely obtained around 30 minutes, reducing the necessity for extending the CBD process by an additional 15 minutes.

Although the oxidation peak heights can be normalised to the FTO peak to provide a numerical comparison of the ratio of coverage for the sonicated samples, the peak heights in a typical cyclic voltammogram can be influenced by non-faradaic charging of the double layer that exists between the FTO electrode and the electrolyte. Thus, differential pulse voltammetry was also carried out on the same samples, and the corresponding voltammograms are presented in Fig. 2c. Differential



pulse voltammetry removes the non-faradaic contribution to the peak height by measuring the current before and at the end of a pulse, and subtracting one from the other.²⁴ From the peaks, the coverage of the SnO₂ was calculated with the following equation:

$$\% \text{ coverage} = 100\% - \left(\frac{J_{\text{peak,DPV}}(\text{SnO}_2)}{J_{\text{peak,DPV}}(\text{FTO})} \right) \times 100\% \quad (1)$$

$J_{\text{peak,DPV}}$ refers to the peak value of the differential current density obtained from the differential pulse voltammogram. The ratio of the peak heights gives the percentage of exposed FTO area in the sonicated SnO₂ films, and thus subtracting the ratio from 100% would give the degree of coverage by SnO₂. This is similar to the ratio suggested by Kavan *et al.*,²¹ except that in the case of the study by Kavan *et al.*, the peak heights from the cyclic voltammograms were used. In our case, the relatively flat oxidation peaks make it hard to discern the exact peak heights. As such, the peak heights from the differential pulse voltammogram were used instead. Nevertheless, the coverage calculations based on the cyclic voltammograms (Table S1†) follow the same trend.

Based on the differential pulse voltammogram peaks, the percentages of coverage for 30-SnO₂ (94.6%) and 45-SnO₂ (92.9%) are also shown to be higher than the coverage for 15-SnO₂ (84.9%). Therefore, this suggests that devices based on 30-SnO₂ and 45-SnO₂ would likely have better efficiencies than 15-SnO₂-based devices. The slight decrease in coverage for 45-SnO₂ may be attributed to large agglomerations that have fallen off the surface of the film during the washing process (see Experimental section below) before annealing. Combining the data collected from different characterisation techniques, we demonstrate that sonication of the CBD bath is able to improve the coverage of SnO₂ on FTO, with a shorter duration of reaction as compared to the standard CBD technique.

Noting the upper limit of coverage by 30 minutes of ultrasonication, another experiment was conducted to see whether the ultrasonication contributes to obtaining coverage of SnO₂ faster than the conventional CBD method (Th-SnO₂, "Thermal"), where the CBD bath is placed in an oven set to 70 °C, following Anaraki *et al.*⁷ For a fair comparison, the

conventional method is done for only 30 minutes to isolate the effect of the ultrasonication. Fig. 2d shows the differential pulse voltammogram of 30-SnO₂ and Th-SnO₂, with the associated cyclic voltammogram shown in Fig. S3.† The coverage for 30-SnO₂ is about (92.4%), compared to the coverage of Th-SnO₂ at (66.1%). The oxidation peak height in the cyclic voltammogram of 30-SnO₂ is also lower than that of Th-SnO₂. This shows that the ultrasonication speeds up the CBD process, and allows for better coverage in a shorter amount of time. The difference in coverage could also be visualized *via* scanning electron microscopy (SEM) technique. Fig. 2e–g show the top-view images of bare FTO, 30-SnO₂, and Th-SnO₂. The bare FTO image shows grains of various sizes with sharp, well-defined boundaries. In contrast, the other two images show several bumps on these FTO grains, blurring the boundaries. The bumps are indicative of a conformal layer of SnO₂ covering the FTO, similar to the visual appearance of the CBD-based SnO₂ reported by Yoo *et al.*¹³ Furthermore, 30-SnO₂ appears peppered with more bumps than Th-SnO₂, suggesting once more the improved coverage brought about by sonication.

X-ray photoelectron spectroscopy

Next, we sought to understand the effects of the sonication on the extent of the deposition reaction. In particular, avoiding excessive reaction is crucial. Yoo *et al.* showed that Sn²⁺, which is detrimental to device performance, forms when the chemical bath deposition time was extended beyond 6 hours.¹³ Thus, X-ray Photoelectron Spectroscopy (XPS) was also done for Th-SnO₂, 15-SnO₂, 30-SnO₂, 45-SnO₂, and as references, SnO₂ powder, and the uncoated substrate. These substrates are FTO substrates on glass, with a region where FTO was etched away, leaving behind a non-conductive glass region. The XPS spectra were measured on this non-conductive region, with the intention to prevent the peaks from crystalline FTO from influencing the XPS data. Fig. 3a shows the survey spectra for the uncoated, bare substrate, 15-SnO₂, 30-SnO₂, and 45-SnO₂. Regions of interests are the Sn 3d peaks and the O 1s peaks, for which high-resolution XPS scans were done (Fig. 3b and c). The presence of the Si 2p peaks in the survey spectra suggests the presence of

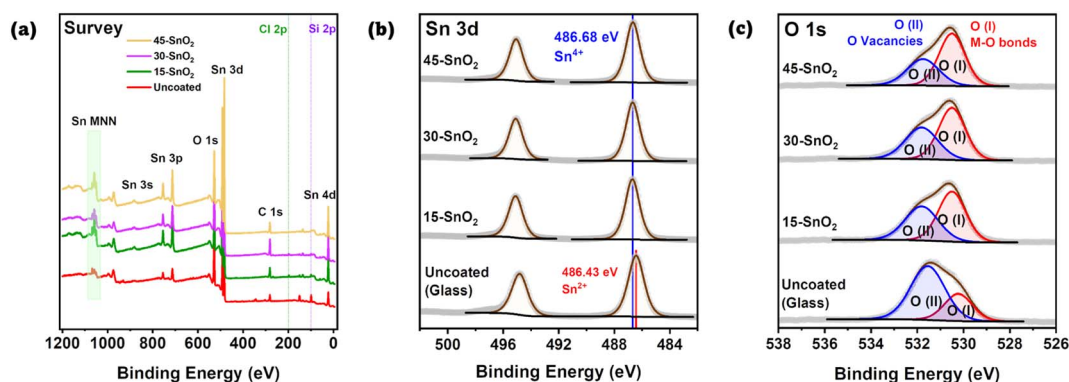
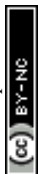


Fig. 3 (a) Survey spectra for all samples. The uncoated sample refers to bare glass substrate. (b) High-resolution XPS data for Sn 3d. Except for the uncoated glass substrate, all SnO₂ samples had similar binding energies corresponding to Sn⁴⁺. (c) High-resolution XPS data for O 1s. O(I) corresponds to lattice oxygen, while O(II) corresponds to oxygen vacancies.



pinholes in the sonicated SnO₂ films, which is in agreement with the cyclic voltammetry and differential pulse voltammetry analysis. The survey spectra for all samples, along with the full high-resolution scans (with Th-SnO₂ and the reference SnO₂) of the Sn 3d peaks and O 1s peaks, can be found in Fig. S4 and S5,† respectively.

Fig. 3b shows the Sn 3d peaks for the three sonicated samples along with an uncoated substrate. Quantification values are provided in Table S2.† No deconvolution was needed for the CBD samples (15-SnO₂, 30-SnO₂, 45-SnO₂). All of the peaks have binding energies close to 486.6 eV,²⁵ likely suggesting the full conversion of Sn²⁺ from the precursor into Sn⁴⁺. To confirm this, XPS of commercial SnO₂ powder was also performed, which showed similar peak energies (Fig. S5†). Since the presence of Sn²⁺ in the films is detrimental to device performance,¹³ this suggests that thus far, the entire process can lead to films without Sn²⁺. The fact that 45-SnO₂ did not contain Sn²⁺, which Yoo *et al.* showed is also an indicator of excessive CBD, shows the possibility of increasing the sonication time or sonication intensity to bring about better coverage. Interestingly, the uncoated substrate also showed Sn 3d peaks, which suggests that during the preparation of the bare substrates, not all of the FTO was etched away. Instead, only enough was etched to ensure that region is non-conductive. Fortunately, these peaks have binding energies closer to Sn²⁺ (486 eV)²⁵ rather than Sn⁴⁺, so the fact that the coated samples seem to comprise only Sn⁴⁺ shows that Sn 3d contributions from the uncoated glass are likely to be negligible, despite the lack of 100% SnO₂ coverage on all sonicated films (as shown in Fig. 2b).

The O 1s spectra (Fig. 3c) for the films could be deconvoluted into 2 regions – marked as O(i) and O(ii), where O(i) refers to the oxygen bonded to metal (M–O) and O(ii) likely refers to the presence of oxygen vacancies.²⁶ The contribution for O(ii) appears to decrease monotonically from uncoated > 15-SnO₂ > 30-SnO₂ > 45-SnO₂. The trend suggests that the monotonic decrease in the contribution for O(ii) from 15-SnO₂ to 45-SnO₂ can be attributed to a decrease in oxygen vacancies, and the incorporation of sonication may lead to films with lower oxygen defect concentrations.

Overall, the cyclic voltammetry and XPS data seem to support the hypothesis that ultrasonication of the CBD solution speeds up the reaction, allowing for improved coverage without causing detrimental effects attributed to the excessive reaction. No Sn²⁺ peaks were present in the sonicated SnO₂ samples, and the amount of oxygen vacancies decreased with sonication time for at least up to 45 minutes of sonication time. This was not the case for the typical CBD process, where Yoo *et al.* showed an increase in oxygen vacancies and Sn²⁺ contribution with increasing CBD time. Therefore, this shows the effectiveness of using ultrasonication to promote faster deposition times. Ultrasonication of the CBD bath promotes heterogenous nucleation due to lower contact angles favouring nucleation,²⁷ increases the diffusion coefficients of precursors,²⁷ and induces asymmetric cavitation, which enable the precursor and nuclei to be directed to the substrates.¹⁶ While Fig. S6† shows the eventual homogeneous nucleation occurring after 30 minutes,

Fig. 2b shows that a film of SnO₂ has already been formed on the substrate, highlighting the preference for heterogenous nucleation over homogeneous nucleation.

Device characterisations

While cyclic voltammetry was able to quantify the extent of coverage of SnO₂, it does not show the locations of the SnO₂-covered areas. Therefore, as a simple and practical test for SnO₂ homogeneity, and with evidence showing the improved coverage of SnO₂ after using ultrasonication to speed up the sonication process, perovskite solar cell devices were then fabricated to see if the improved coverage also translates to better cell efficiencies. We expect that a more uniform nucleation would translate into a greater number of working devices since we have four cells on one substrate. Furthermore, fewer pinholes on the SnO₂ layer would mean better charge extraction, and lower possibility of recombination between the FTO and perovskite where there is no SnO₂.²²

Firstly, solar cells based on the “triple cation” perovskite composition with n-i-p architecture (where planar SnO₂ and Spiro-OMeTAD were used as electron- and hole-transporting materials, respectively) were fabricated. The SnO₂ layers were deposited *via* CBD using both sonication method and the conventional method (Th-SnO₂). More details of the experiment can be found in the Experimental section. Similar durations were used for both sonicated and oven (Th-SnO₂) methods, allowing for an equivalent comparison of the rate of the CBD reaction to be made.

Fig. S7† shows the distributions of V_{OC} , J_{SC} , FF, and PCE for all cells, revealing the failed cells associated primarily with Th-SnO₂. These failed cells are either shunted, or have suppressed V_{OC} and FF likely due to high recombination (Fig. S8†). Assuming the same quality of perovskite and Spiro-OMeTAD layers, the results suggest that use of ultrasonication in the CBD process contributes to the formation of a better quality SnO₂ layer in the device, which ultimately results in PSCs with higher PCEs. The higher PCE values for the sonicated samples are brought about by an increase across the average open-circuit potential (V_{OC}) and the fill factor (FF) of the cells. IPCE data are provided in Fig. S9.† The similar transmission spectra in Fig. S10† also show that the degree of coverage did not significantly affect the light reaching the perovskite layer, so optical properties are unlikely a factor in the observed device performance trends. The FF value is associated with the series and shunt resistances within the devices. Any pinholes in the SnO₂ layer would mean that the perovskite layer may come in contact with the transparent conducting oxide layer, facilitating recombination and decreasing the shunt resistance value.⁷ As the sonicated-based devices exhibit higher shunt resistances relative to the oven ones (Fig. 4e), it can be concluded that ultrasonication helps improve the SnO₂ coverage during the coating process.

The greater number of working devices for the sonicated samples compared to Th-SnO₂ also suggests that more uniform nucleation occurs due to ultrasonication. However, the negligible difference in yields amongst the devices made from 15-



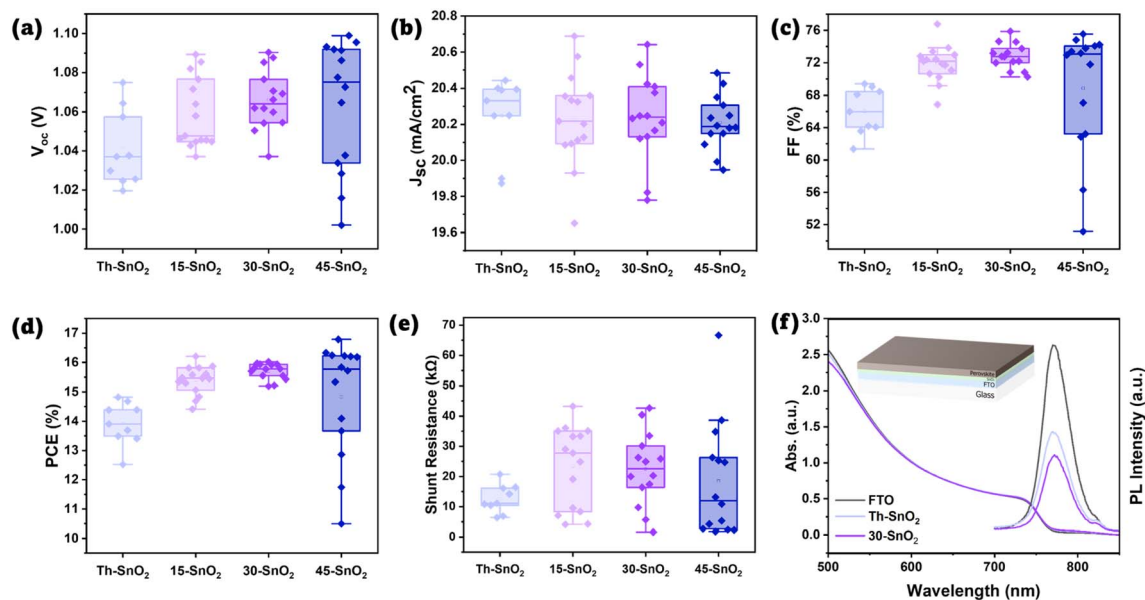


Fig. 4 (a–e) Boxplots of device properties (V_{oc} , J_{sc} , FF, PCE, and estimated shunt resistance, respectively). (f) UV-vis and PL spectra of perovskite coated on FTO, Th-SnO₂, and 30-SnO₂. Inset diagram shows the tested device architecture. Colour scheme is the same as that for Fig. 1b.

SnO₂, 30-SnO₂, and 45-SnO₂ films suggests that increasing the sonication time does not help increase the nucleation rate. As mentioned previously, there are two stages in the deposition process for CBD of CdS films.¹¹ The first stage is an ion-by-ion deposition of precursors on the substrate, which eventually grows into a compact, adherent layer. The second stage is the physical deposition of large agglomerations of CdS particles, which forms a poorly adhering rough layer on top of the compact layer. While we do not have evidence of the ion-by-ion deposition process in the case of SnO₂, we do have evidence of the agglomeration from the cross-sectional SEM image of one of the devices (Fig. S11†). The presence of the poorly adhering layer suggests that homogeneous nucleation (and growth) has occurred. This layer breaks up easily when the substrates are sonicated in deionised water after the CBD process. Therefore, it does not improve the hole-blocking function of the electron-transporting layer in devices. Yet, because the rate of homogeneous nucleation is now comparable to heterogeneous nucleation, this also means that the rate of heterogeneous nucleation and growth will be reduced, as both homogeneous and heterogeneous processes will compete for precursors (conservation of mass), which would therefore affect the final coverage of the compact, adherent SnO₂ layer. Therefore, a possible way to further increase the yields would be to increase the concentration or ultrasonication intensity, which would help to increase the nucleation rate at the beginning²⁷ without triggering homogeneous nucleation too early in the process.

Fig. 4a–e show the distribution of the various photovoltaic parameters after excluding failed devices (defined as <10% PCE), for a fairer comparison of the median values. A more detailed discussion can be found in the ESI.† Fig. S12a and b† show the boxplots for estimated series resistance and hysteresis index for working cells. From Fig. 4a–e, it can be observed that even after 15 min, the device properties of 15-

SnO₂ were better than that of Th-SnO₂. At 30 and 45 min, it appears that the coverage is roughly similar, although both are poorer than that for 15-SnO₂. The large difference in percentage is caused by 1 additional cell failing in 30-SnO₂ and 45-SnO₂, suggesting that the difference may be negligible. The apparent contradiction with Fig. 2b may be explained by the fact that the devices do not cover every area of the substrate. The median device PCEs for 30-SnO₂ ($\eta = 15.78\%$) is still better than that for 15-SnO₂ ($\eta = 15.45\%$), suggesting that even if the difference in yield (*via* percentage) is significant, the higher PCE comes about as a trade-off, and 30-SnO₂ is the optimal point according to this data. This trend can also be explained by the competing homogeneous and heterogeneous processes, as the degree of SnO₂ coverage will affect the device efficiency due to recombination at the FTO-perovskite interface.²² Larger precipitates were spotted through cross-sectional SEM for 45-SnO₂ as mentioned earlier, although not spotted in the others (Fig. S11 and S13†), suggesting that the sonication step after CBD may need to be extended to ensure that more of these large precipitates are removed.

Correspondingly, we observe a larger spread of data for 45-SnO₂, with the highest and lowest V_{oc} , FF, and therefore PCE. Yet, the median PCE for 45-SnO₂ is lower than that for 30-SnO₂ despite the highest V_{oc} obtained. This is due to the spread of V_{oc} and FF values. The large precipitates can exceed 100 nm as seen in Fig. S11,† thus creating possible shunting pathways (if the grains were larger) or possible increased local defects near the precipitate, leading to the reduced V_{oc} . Conversely, in other areas of 45-SnO₂ without the large precipitates, coverage may be almost complete, leading to the highest V_{oc} . Such a spread of device efficiencies over small areas is undesirable, and it appears that unless the onset of the rapid increase in homogeneous nucleation can be delayed, 30-SnO₂ provides the best



trade-off in terms of surface coverage and duration of the CBD process.

Corroborating with the FF trend, lower V_{OC} values in the oven samples compared to the sonicated ones can also be attributed to the poorer ETL coverage. As mentioned, poor coverage implies that some of the FTO is in direct contact with the perovskite, providing a region for non-radiative electron-hole recombination to occur.²² To test this hypothesis, steady-state photoluminescence measurement was done on perovskite samples coated on glass, on bare FTO, on FTO/30-SnO₂/PVK and FTO/Th-SnO₂/PVK, and the spectra are presented in Fig. 4f. The suppressed PL peak of the FTO/30-SnO₂/PVK suggests a large degree of charge transfer from the perovskite to the ETL. On the other hand, while the PL peak for FTO/Th-SnO₂/PVK is lower than that from FTO/PVK, which is indicative of some degree of ETL coverage, the peak height is still lower than that of FTO/30-SnO₂/PVK, again suggesting that coverage is poorer with the oven-based, non-sonicated ETL compared to the sonicated SnO₂. Fig. S14 and S15† show the XRD and GIWAXS data for the perovskite coated on both Th-SnO₂ and 30-SnO₂ to highlight that the perovskites are similar, and thus the UV-vis and PL data are comparable.

Finally, an additional experiment was performed to compare the performances of devices made with the ultrasonication-assisted CBD method against those based on a spin-coated colloidal SnO₂ precursor (Fig. S16†). The ultrasonication-assisted CBD-based devices had higher reproducibility, hence showing the viability of the ultrasonication-assisted CBD, with speed and reproducibility as advantages over other methods for SnO₂ deposition.

Conclusions

The above data suggest that a 30 minute sonicated-CBD process would be ideal for the fabrication of ETL films for perovskite solar cells, assuming that conditions are similar to the ones used in this paper. Several devices made from 45-SnO₂ have efficiencies that outperform those fabricated with 30-SnO₂, which suggests that further optimisation is necessary. A combination of methods used in the existing literature to improve CBD can be used in conjunction with sonication to further improve the quality of the SnO₂ films. However, for the purpose of this study, it has been demonstrated as proof-of-concept that sonication can help speed up the CBD reaction without sacrificing the quality of the SnO₂ films made. The optimal duration for CBD sonication is dependent on maximising the rate of heterogeneous nucleation, whilst reducing the rate of homogeneous nucleation. Tweaking the various other factors that affect the chemical bath deposition in general (pH, temperature) are likely to help improve the quality of SnO₂ films formed by the ultrasonication method. In conclusion, our work has demonstrated that ultrasonication is able to speed up the CBD process without sacrificing the quality of the SnO₂ films, thus aligning the eventual goal of commercialisation. More work on incorporating the various other strategies employed by other research groups can also be done, all with the eventual aim of rapid fabrication of SnO₂ ETLs.

Experimental

SnO₂ film fabrication

An amount of 0.250 g of urea (Sigma-Aldrich, ACS reagent, ≥99%) was dissolved in 200 mL of DI water in a clean glass beaker, and shaken until fully dissolved. A volume of 5 μL of thioglycolic acid (Sigma-Aldrich, anhydrous 99%) and 250 μL of 37 wt% HCl (Sigma-Aldrich) were then added to the solution, and shaken. An amount of 0.150 g of SnCl₂·2H₂O (Sigma-Aldrich, ≥99.995% trace metals basis), corresponding to 0.0033 M, was then added to the solution and shaken. Other concentrations were also attempted (0.012 M, 0.12 M). A detailed discussion can be found in the ESI (Fig. S17 and S18†). The precursor solution was then sonicated at room temperature for 40 minutes for mixing (Elma EH120), with the temperature of the water never rising above 34 °C. Afterwards, the beaker was removed, and substrates were placed vertically in the solution using a Teflon holder. For the oven control, the beaker was placed in a convection oven at 70 °C for 30 minutes. For the sonicated samples, the beaker was placed in another ultrasonicator (Soltec Sonica 5300, 500 W) with the water bath maintained at 70 °C. The sonicator was then turned on for 15, 30, or 45 minutes. After the CBD process, the substrates were removed, rinsed with DI water, and then sonicated again in DI water for 3 minutes to remove the poor adherent SnO₂ precipitates on the FTO substrates. Finally, the substrates were dried and annealed at 180 °C for 1 h.

Device fabrication

Pre-etched FTO substrates were washed in Decon soap, DI water, acetone, and ethanol for 15 minutes each. The substrates were then UV-ozone treated for 30 minutes at 100 °C before SnO₂ ETL deposition, as described above. After the deposition, the substrates were UV-ozone treated again for 20 minutes before perovskite deposition. Mass amounts of 18 mg CsI (99.99% trace metals basis), 25.4 mg MABr (GreatCell Solar), 84.7 mg PbBr₂ (TCI, 99.99% trace metals basis), 198.5 mg FAI (GreatCell Solar) and 585.1 mg PbI₂ (TCI, 99.99% trace metals basis) were dissolved in 1 mL of 8 : 2 DMF : DMSO (DMF: Sigma-Aldrich, anhydrous 98.8%, DMSO: Sigma-Aldrich, anhydrous, ≥99.9%) prior to deposition, and left on the hotplate at 50 °C for 2 h before use. A two-step spin-coating process was used. After addition of the perovskite precursor on the substrate, the substrate was spun at 1000 rpm for 10 s and 6000 rpm for 20 s, with chlorobenzene dripped onto the substrate 5 s before the end of the entire spin-coating process. The substrates were then annealed at 100 °C for 1 h. Spiro-OMeTAD solution was then spin-coated onto the perovskite film (72.3 mg Spiro-OMeTAD (Lumtech), 28.5 μL tBP (Sigma-Aldrich, 98%), 17.5 μL Li-TFSI (99.95% trace metals basis) in ACN (Sigma-Aldrich), in 1 mL chlorobenzene) at 4000 rpm for 30 s. Finally, 100 nm of gold electrical contacts were evaporated onto the devices using a thermal evaporator.

Characterisations

JV scans were obtained with a Keithley 2612B SourceMeter and Newport 94043A Solar Simulator (450 W xenon), which provided an illumination intensity of 1000 W m⁻², AM 1.5 G spectral



distribution. A shadow mask of size 0.086 cm^2 was used, with a scan rate of approximately 300 mV s^{-1} .

For cyclic voltammetry and differential pulse voltammetry, the substrates were first taped up such that the exposed surface area is 1.7 cm^2 (based on the width of the pre-etched FTO substrate). The substrates were then dipped into a $10\text{ mM } [\text{Fe}(\text{CN})_6]^{3-}/[\text{Fe}(\text{CN})_6]^{4-}$ redox couple ($\text{K}_3\text{Fe}(\text{CN})_6$: $>99.0\%$, $\text{K}_4\text{Fe}(\text{CN})_6$: $98.5\text{--}102.0\%$, both from Sigma-Aldrich) with 1 M of KCl (Sigma-Aldrich, $99.0\text{--}100.5\%$). A platinum wire was used as the counter-electrode, and a 1 M Ag/AgCl electrode was used as the reference electrode. The electrolyte was purged with N_2 gas for 40 minutes before starting the measurement. A Metrohm Autolab PGSTAT302N was used. For cyclic voltammetry, 3 cycles were scanned from 1.4 V to -1 V or -0.2 V , with a scan rate of 100 mV s^{-1} , and the third cycle was used. For differential pulse voltammetry, the substrate was scanned from -0.2 V or -1 V to 1.4 V , with a step size of 0.005 V , modulation amplitude of 0.02 V , at 25 Hz .

SEM images of films were all obtained using a field emission scanning electron microscope (FESEM), model JOEL JSM 6700F.

Steady-state photoluminescence was performed with a Horiba FluoroMax Spectrometer. The samples were excited at 600 nm and scanned from 700 nm to 850 nm (increment of 1 nm), with a slit width of 10 nm for both source and detector.

UV-vis absorbance spectra were measured with a Shimadzu UV2600 spectrometer, and scanned from 850 nm to 300 nm with a step size of 0.1 nm .

GIWAXS spectra were obtained with a Xenocs Nano-inXider with a PILATUS3 $3 \times 100\text{ K}$ detector and $\text{Cu K}\alpha_1$ radiation. For the perovskite-coated half-stack device (FTO + ETL + perovskite only), the normal out-of-plane configuration ($\varphi = 0^\circ$) was adopted at a grazing angle of 4° . Data were analysed with the Foxtrot programme that was bundled with the Nano-inXider.

X-ray photoelectron spectroscopy (XPS) analysis was performed using an AXIS Supra spectrometer (Kratos Analytical Inc., UK) equipped with a hemispherical analyser and a monochromatic Al K-alpha source (1487 eV) operated at 15 mA and 15 kV . The XPS spectra were acquired from an area of $700 \times 300\text{ }\mu\text{m}^2$ with a take-off angle of 90° . Pass energies of 160 eV and 20 eV were used for the survey and high-resolution scans, respectively. A 3.1 volt bias was applied to the sample to neutralise charge build-up on the sample surface. The binding energies (BEs) were charge-corrected based on the C $1s$ of adventitious carbon at 284.8 eV , and verified with the O $1s$ of the metal oxide peak at 530.5 eV . As reference, XPS measurements of commercially-available SnO_2 (Sigma-Aldrich, ~ 325 mesh, 99.9% trace metals basis) powder were also performed.

Conflicts of interest

The authors declare the following competing financial interest(s): N. M. is the director of Prominence Photovoltaics Pte Ltd., a perovskite solar cell commercialisation company.

Acknowledgements

This research was funded by the National Research Foundation, Prime Minister's Office, Singapore through the Intra-CREATE

Collaborative Grant (NRF2018-ITC001-001), and Ministry of Education Tier 2 Project (MOE2019-T2-2-097). The X-ray Photoelectron Spectroscopy work was performed at the Facility for Analysis, Characterisation, Testing and Simulation (FACTS), Nanyang Technological University, Singapore.

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